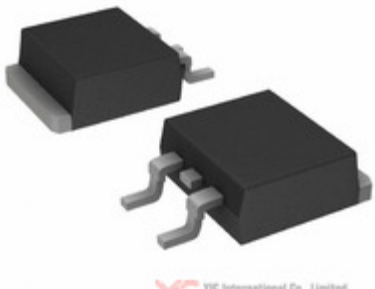
	<p><b>SUD06N10-225L-GE3</b></p>
	<p><b>Hersteller-Teilenummer:</b> SUD06N10-225L-GE3</p> <p><b>Hersteller / Marke:</b> Electro-Films (EFI) / Vishay</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 100V 6.5A DPAK</p> <p><b>Datenblätter:</b> <a href="#">1.SUD06N10-225L-GE3.pdf</a> <a href="#">2.SUD06N10-225L-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 35181 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	SUD06N10-225L-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 100V 6.5A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	35181 pcs Stock
detaillierte Beschreibung	N-Channel 100V 6.5A (Tc) 1.25W (Ta), 16.7W (Tc)
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252AA
Verlustleistung (max)	1.25W (Ta), 16.7W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6.5A (Tc)
Rds On (Max) @ Id, Vgs	200 mOhm @ 3A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	4nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	240pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Cut Tape (CT)
Basisteilenummer	SUD06N10
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SUD06N10-225L-GE3CT

SUD06N10-225L-GE3 ist neu im Original. Suche SUD06N10-225L-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD06N10-225L-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SUD06N10-225L-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>SUD08P06-155L</b> VISHAY SUD08P06-155L VISHAY</p>	 <p><b>SUD06N10-225L-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 100V 6.5A DPAK</p>	 <p><b>SUD08P06-155L-E3</b> Vishay / Siliconix MOSFET P-CH 60V 8.4A DPAK</p>	 <p><b>SUD06N10-225L-E3</b> Vishay / Siliconix MOSFET N-CH 100V 6.5A DPAK</p>
 <p><b>SUD06N10-225L</b> VISHAY SUD06N10-225L VISHAY</p>	 <p><b>SUD06N10-255L-T1-E3</b> V SUD06N10-255L-T1-E3 V</p>	 <p><b>SUD06N10-225L-GE3</b> Vishay / Siliconix MOSFET N-CH 100V 6.5A DPAK</p>	 <p><b>SUD06N10-225L-T1-E3</b> VB SUD06N10-225L-T1-E3 VB</p>

### heiße Teile

Mehr

⊛ SUD06N10-225L	↔ SUD06N10-225L-E3	⇒ SUD06N10-225L-E3	D SUD06N10-225L-GE3	↔ SUD06N10-225L-T1-E3
⊣ SUD06N10-225L_08	⊛ SUD06N10-255L-T1-E3	D SUD08P06-155L	⇒ SUD08P06-155L-E3	↔ SUD08P06-155L-E3
⊛ SUD08P06-155L-GE3	⊣ SUD08P06-155L-GE3	⊛ SUD08P06-155L-T4E3	↔ SUD08P06-155L-T4E3	↔ SUD09P10-195
D SUD09P10-195-GE3	⊛ SUD09P10-195-GE3	⊣ SUD10P06-280L	⊛ SUD10P06-280L-E3	↔ SUD15N06
⇒ SUD15N06-09L-GE3	↔ SUD15N06-90	⊛ SUD15N06-90-T1-E3	⊣ SUD15N06-90L	↔ SUD15N06-90L-E3
↔ SUD15N06-90L-T1-E3	⇒ SUD15N06-90L-T4	D SUD15N15-95	⊛ SUD15N15-95-E3	⊣ SUD15N15-95-E3
⊛ SUD15P01-52-E3	D SUD17N25-165	⇒ SUD17N25-165-E3	↔ SUD17N25-165-E3	↔ SUD17N25-165-T1-E3
⊣ SUD17N25-165-T4-E3	⊛ SUD19N20	↔ SUD19N20-90	⇒ SUD19N20-90-E2	↔ SUD19N20-90-E3
⊛ SUD19N20-90-E3	⊣ SUD19N20-90-T4-E3	⊛ SUD19N20-90-T4-E3	D SUD19P06	↔ SUD19P06-155L
↔ SUD19P06-60	⊛ SUD19P06-60-E3	⊣ SUD19P06-60-E3	⊛ SUD19P06-60-GE3	↔ SUD19P06-60-GE3

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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